

Isc N-Channel MOSFET Transistor

IXTK200N10L2

• FEATURES

- With To-3PL package
- Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

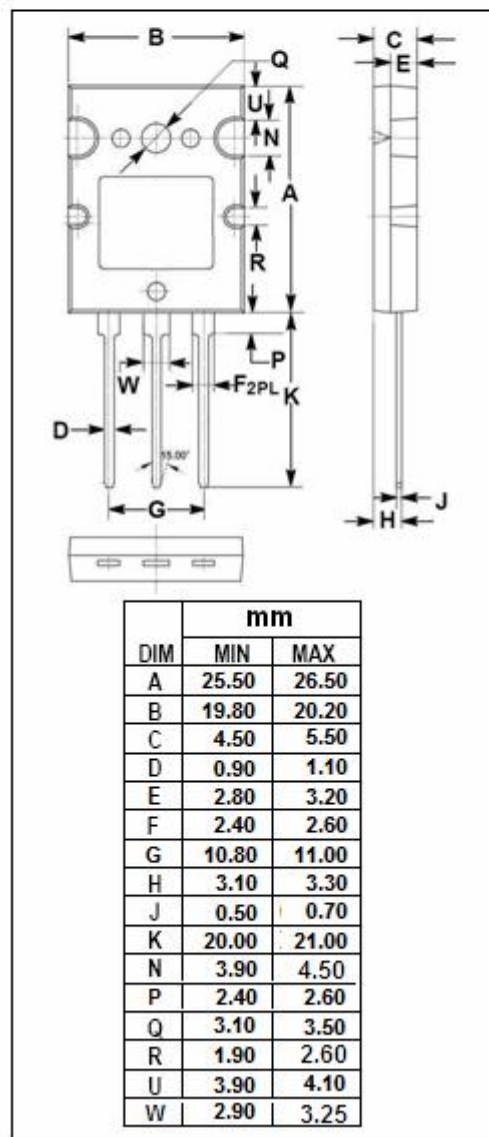
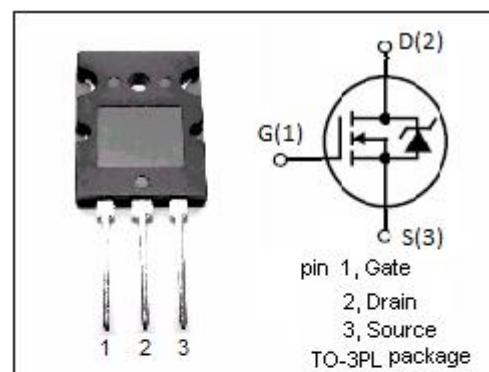
- Switching applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-Continuous	200	A
I_{DM}	Drain Current-Single Pulsed	500	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	1040	W
T_{ch}	Max. Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.12	$^\circ\text{C/W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62	$^\circ\text{C/W}$



Isc N-Channel MOSFET Transistor**IXTK102N30P****ELECTRICAL CHARACTERISTICS** $T_c=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=1mA$	100			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D=3mA$	2.0		4.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=100A$			11	m Ω
I_{GSS}	Gate-Source Leakage Current	$V_{GS}= \pm 20V; V_{DS}=0V$			± 0.2	μA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=100V; V_{GS}=0V; T_j=25^{\circ}\text{C}$ $V_{DS}=100V; V_{GS}=0V; T_j=150^{\circ}\text{C}$			10 250	μA
V_{SDF}	Diode forward voltage	$I_{SD}=100A, V_{GS}=0V$			1.4	V

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